

HIGH DENSITY MOUNTING PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



DESCRIPTION

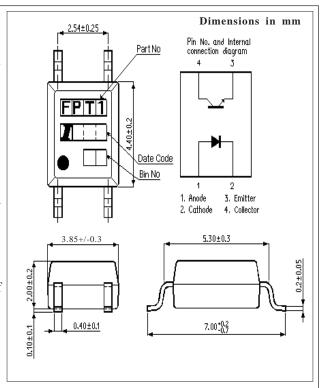
The IS121 is an optically coupled isolator consisting of an infrared light emitting diode and NPN silicon photo transistor in a space efficient dual in line plastic package.

FEATURES

- Marked as FPT1.
- Current Transfer Ratio MIN. 50%
- $Isolation Voltage (3.75kV_{RMS}, 5.3kV_{PK}) \\ All electrical parameters 100\% tested$
- Drop in replacement for Toshiba TLP121

APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



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ABSOLUTEMAXIMUMRATINGS (25°C unless otherwise specified)

Storage Temperature:	55°C to + 150°C
Operating Temperature:	55° C to $+100^{\circ}$ C
Lead Soldering Temperature	
$(1/16 \operatorname{inch} (1.6 \operatorname{mm}) \operatorname{from} \operatorname{case} \operatorname{for} 10 \operatorname{s}$	ecs) 260°C

INPUTDIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUTTRANSISTOR

Collector-emitter Voltage BV _{CEO}	80V
Emitter-collector Voltage BV _{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWERDISSIPATION

Total Power Dissipation	170mW
(derate linearly 2.26mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ Unless otherwise noted)

	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	$I_F = 20 \text{mA}$
	Reverse Current (I_R)			10	μΑ	$V_{_{\rm R}}{=}4V$
Output	$Collector-emitter Breakdown (BV_{CEO})$	80			V	$I_{\rm C}$ =0.1mA
	$Emitter-collector Breakdown (BV_{ECO}\\ Collector-emitter Dark Current (I_{CEO})$			100	V nA	$I_{\scriptscriptstyle E} = 10 \mu A \\ V_{\scriptscriptstyle CE} = 20 V$
Coupled	Current Transfer Ratio (CTR)	50		600	%	$5\text{mAI}_{_{\mathrm{F}}},5\text{VV}_{_{\mathrm{CE}}}$
	Optiional CTR Grades: IS121A IS121B IS121C IS121D IS121GB Collector-emitter Saturation Voltage $V_{\rm CE(SAT)}$ Input to Output Isolation Voltage $V_{\rm ISO}$	80 130 200 300 100 3750 5300		160 260 400 600 0.2 V _{RMS}	% % % % V	$\begin{array}{l} 5\text{mA}I_{\text{F}}, 5\text{V}V_{\text{CE}} \\ 20\text{mA}I_{\text{F}}, 1\text{mA}I_{\text{C}} \\ \end{array}$ See note 1
	Input-output Isolation Resistance R_{ISO} Output Rise Time tr Output Fall Time tf	5x10 ¹⁰	4 3	18 18	Ω μs μs	$V_{IO} = 500 V \text{ (note 1)}$ $V_{CE} = 2V$, $I_{C} = 2\text{mA}$, $R_{L} = 100 \Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.

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